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#### GENERAL PURPOSE AMPLIFIER

#### **RoHS Compliant & Pb-Free Product**

#### **Typical Applications**

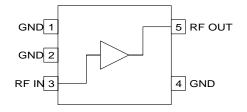
- Broadband, Low Noise Gain Blocks
- IF or RF Buffer Amplifiers
- Driver Stage for Power Amplifiers

#### **Product Description**

The RF2333 is a general purpose, low-cost RF amplifier IC. The device is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process, and has been designed for use as an easily-cascadable  $50\Omega$  gain block. Applications include IF and RF amplification in wireless voice and data communication products operating in frequency bands up to 6000MHz. The device is self-contained with  $50\Omega$  input and output impedances and requires only two external DC biasing elements to operate as specified. The RF2333 is available in a very small industry-standard SOT23-5 surface mount package, enabling compact designs which conserve board space.

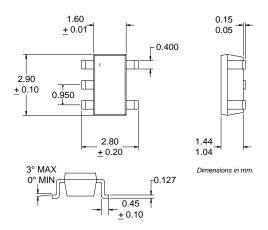
#### **Optimum Technology Matching® Applied**

🗌 Si BJT	🗹 GaAs HBT	GaAs MESFET
Si Bi-CMOS	SiGe HBT	Si CMOS
InGaP/HBT	🔲 GaN HEMT	SiGe Bi-CMOS



#### **Functional Block Diagram**

- Final PA for Low Power Applications
- Broadband Test Equipment



#### Package Style: SOT23-5

#### **Features**

- DC to 6000MHz Operation
- Internally matched Input and Output
- 10dB Small Signal Gain
- +34dBm Output IP3
- +18.5dBm Output Power
- Good Gain Flatness

#### Ordering Information RF2333 General Purpose Amplifier RF2333 PCBA Fully Assembled Evaluation Board RF Micro Devices, Inc. Tel (336) 664 1233 7628 Thorndike Road Fax (336) 664 0454 Greensboro, NC 27409, USA http://www.ffmd.com

#### **Absolute Maximum Ratings**

Parameter	Rating	Unit		
Input RF Power	+13	dBm		
Operating Ambient Temperature	-40 to +85	°C		
Storage Temperature	-60 to +150	°C		

Caution! ESD sensitive device.

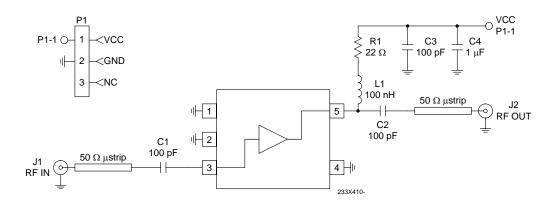
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Parameter	Specification		Unit	Condition		
Faiallelei	Min.	Тур.	Max.	Unit	Condition	
Overall					T=25°C, V <sub>D</sub> =5.5V, I <sub>CC</sub> =70mA	
Frequency Range		DC to 6000		MHz		
3dB Bandwidth		6		GHz		
Gain		11.2		dB	Freq=100MHz	
		11		dB	Freq=1000MHz	
		10.4		dB	Freq=2000MHz	
		10.2		dB	Freq=3000MHz	
		10			Freq=4000MHz	
		9.2			Freq=5000MHz	
		8.3			Freq=6000MHz	
Gain Flatness		±0.4		dB	100MHz to 2000MHz	
Noise Figure		8.2		dB	Freq=2000MHz	
Input VSWR		1.7:1			In a 50 $\Omega$ system, DC to 4000MHz	
Output VSWR		1.7:1			In a 50 $\Omega$ system, DC to 4000 MHz	
Output IP <sub>3</sub>		+34.5		dBm	Freq=1000MHz±50kHz, P <sub>TONE</sub> =-10dBm	
Output P <sub>1dB</sub>		+18.5		dBm	Freq=1000MHz	
Reverse Isolation		17		dB	Freq=2000MHz	
Thermal					I <sub>CC</sub> =70mA, P <sub>DISS</sub> =368mW (See Note.)	
Theta <sub>JC</sub>		247		°C/W		
Maximum Measured Junction Temperature		176		°C	T <sub>AMB</sub> =+85°C, V <sub>PIN</sub> =5.26V	
Mean Time Between Failures		350		years	See Note.	
Power Supply					With $22\Omega$ bias resistor	
Device Operating Voltage		5.3		V	V At pin 5 with I <sub>CC</sub> =70mA	
Supply Voltage		6.9		V	At evaluation board connector, I <sub>CC</sub> =70mA	
Operating Current			70	mA	See note.	

Note: Because of process variations from part to part, the current resulting from a fixed bias voltage will vary. As a result, caution should be used in designing fixed voltage bias circuits to ensure the worst case bias current does not exceed 70mA over all intended operating conditions.

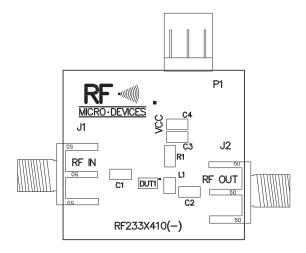
Pin	Function	Description	Interface Schematic
1	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
2	GND	Same as pin 1.	
3	RF IN	RF input pin. This pin is NOT internally DC-blocked. A DC-blocking capacitor, suitable for the frequency of operation, should be used in most applications. DC coupling of the input is not allowed, because this will override the internal feedback loop and cause temperature instability.	
4	GND	Same as pin 1.	
5	RF OUT	RF output and bias pin. Biasing is accomplished with an external series resistor and choke inductor to $V_{CC}$ . The resistor is selected to set the DC current into this pin to a desired level. The resistor value is determined by the following equation: $R = \frac{(V_{SUPPLY} - V_{DEVICE})}{I_{CC}}$ Care should also be taken in the resistor selection to ensure that the current into the part never exceeds 70mA over the planned operating temperature. This means that a resistor between the supply and this pin is always required, even if a supply near 5.5V is available, to provide DC feedback to prevent thermal runaway. Because DC is present on this pin, a DC-blocking capacitor, suitable for the frequency of operation, should be used in most applications. The supply side of the bias network should also be well bypassed.	

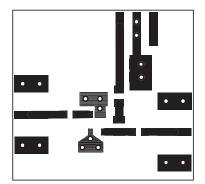
### **Evaluation Board Schematic**

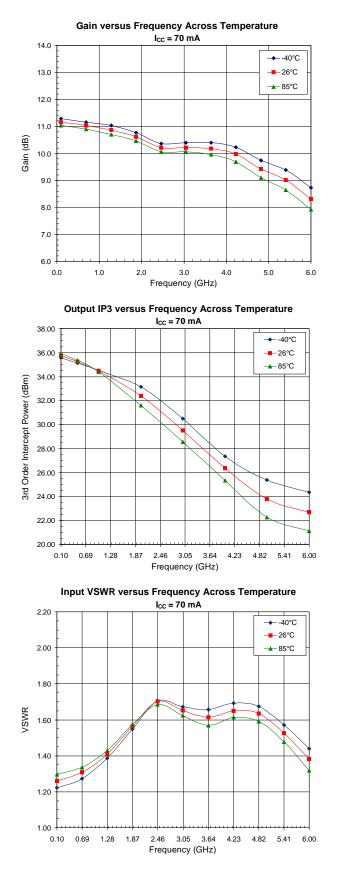


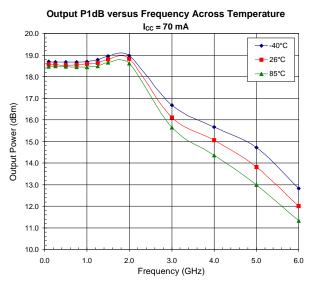
### Evaluation Board Layout Board Size 1.0" x 1.0"

Board Thickness 0.020", Board Material R0-4003 Rogers

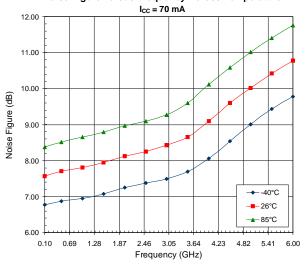




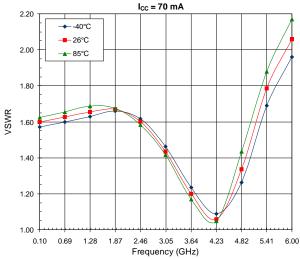


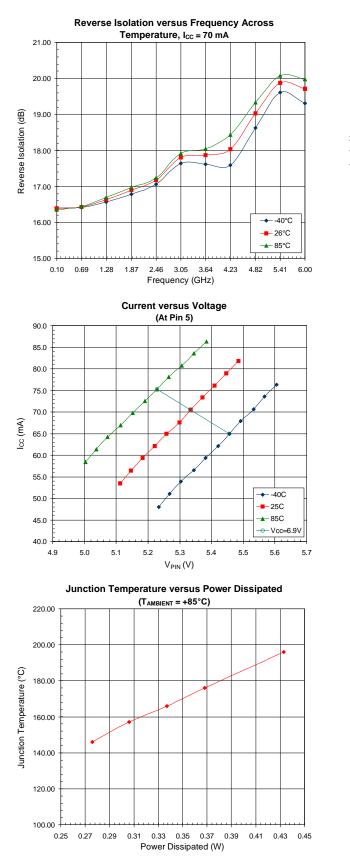


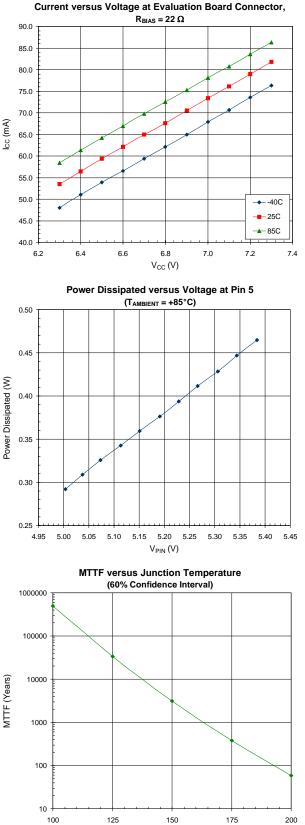
Noise Figure versus Frequency Across Temperature



Output VSWR versus Frequency Across Temperature







Junction Temperature (°C)

4-270